

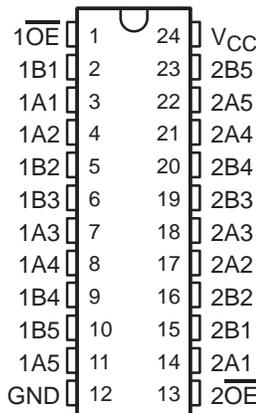
# SN74CBTD3384C

## 10-BIT FET BUS SWITCH WITH LEVEL SHIFTING 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

SCDS133A – SEPTEMBER 2003 – REVISED OCTOBER 2003

- Undershoot Protection for Off-Isolation on A and B Ports Up To –2 V
- Integrated Diode to  $V_{CC}$  Provides 5-V Input Down To 3.3-V Output Level Shift
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance ( $r_{on}$ ) Characteristics ( $r_{on} = 3 \Omega$  Typical)
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion ( $C_{iO(OFF)} = 5 \text{ pF}$  Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- $V_{CC}$  Operating Range From 4.5 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels (0.8-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, 3.3-V, 5-V)
- Control Inputs Can be Driven by TTL or 5-V/3.3-V CMOS Outputs
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating

DB, DBQ, DGV, DW, OR PW PACKAGE  
(TOP VIEW)



### description/ordering information

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
–40°C to 85°C	SOIC – DW	Tube	SN74CBTD3384CDW	
		Tape and reel	SN74CBTD3384CDWR	
	SSOP – DB	Tube	SN74CBTD3384CDB	
		Tape and reel	SN74CBTD3384CDBR	
	SSOP (QSOP) – DBQ	Tape and reel	SN74CBTD3384CDBQR	CBTD3384C
	TSSOP – PW	Tube	SN74CBTD3384CPW	CC384C
Tape and reel		SN74CBTD3384CPWR		
TVSOP – DGV	Tape and reel	SN74CBTD3384CDGVR	CC384C	

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).



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# SN74CBTD3384C

## 10-BIT FET BUS SWITCH WITH LEVEL SHIFTING

### 5-V BUS SWITCH WITH $-2\text{-V}$ UNDERSHOOT PROTECTION

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#### description/ordering information (continued)

The SN74CBTD3384C is a high-speed TTL-compatible FET bus switch with low ON-state resistance ( $r_{on}$ ), allowing for minimal propagation delay. This device features an integrated diode in series with  $V_{CC}$  to provide level shifting for 5-V input down to 3.3-V output levels. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBTD3384C provides protection for undershoot up to  $-2\text{ V}$  by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBTD3384C is organized as two 5-bit bus switches with separate output-enable ( $1\overline{OE}$ ,  $2\overline{OE}$ ) inputs. It can be used as two 5-bit bus switches or as one 10-bit bus switch. When  $\overline{OE}$  is low, the associated 5-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{OE}$  is high, the associated 5-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

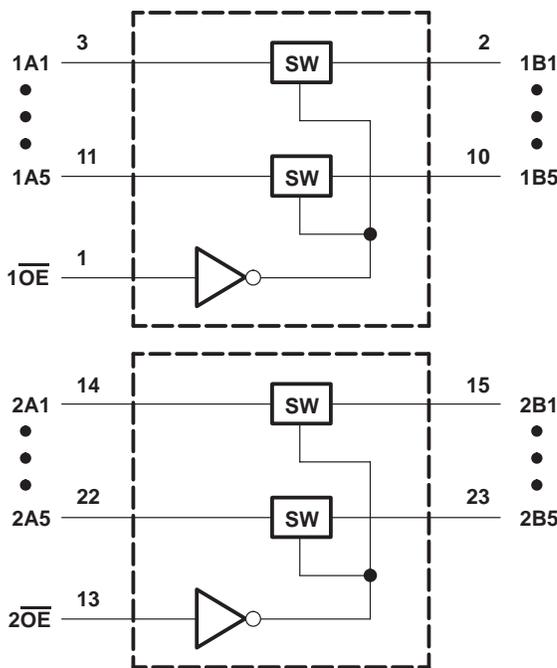
This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE  
(each 5-bit bus switch)

INPUT $\overline{OE}$	INPUT/OUTPUT A	FUNCTION
L	B	A port = B port
H	Z	Disconnect

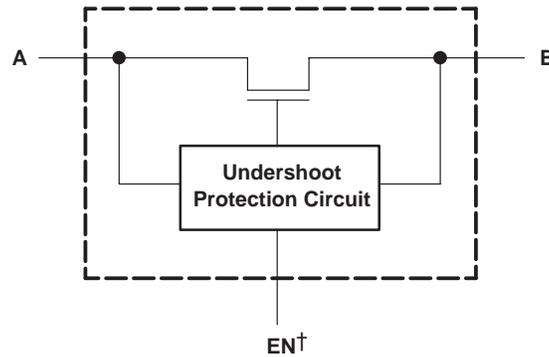
#### logic diagram (positive logic)



**SN74CBTD3384C**  
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**simplified schematic, each FET switch (SW)**



† EN is the internal enable signal applied to the switch.

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡**

Supply voltage range, $V_{CC}$ .....	–0.5 V to 7 V
Control input voltage range, $V_{IN}$ (see Notes 1 and 2) .....	–0.5 V to 7 V
Switch I/O voltage range, $V_{I/O}$ (see Notes 1, 2, and 3) .....	–0.5 V to 7 V
Control input clamp current, $I_{IK}$ ( $V_{IN} < 0$ ) .....	–50 mA
I/O port clamp current, $I_{I/OK}$ ( $V_{I/O} < 0$ ) .....	–50 mA
ON-state switch current, $I_{I/O}$ (see Note 4) .....	±128 mA
Continuous current through $V_{CC}$ or GND terminals .....	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 5): DB package .....	63°C/W
DBQ package .....	61°C/W
DGV package .....	86°C/W
DW package .....	46°C/W
PW package .....	88°C/W
Storage temperature range, $T_{stg}$ .....	–65°C to 150°C

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.  
2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.  
3.  $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ .  
4.  $I_I$  and  $I_O$  are used to denote specific conditions for  $I_{I/O}$ .  
5. The package thermal impedance is calculated in accordance with JESD 51-7.

**recommended operating conditions (see Notes 6 and 7)**

	MIN	MAX	UNIT
$V_{CC}$ Supply voltage	4.5	5.5	V
$V_{IH}$ High-level control input voltage	2	5.5	V
$V_{IL}$ Low-level control input voltage	0	0.8	V
$V_{I/O}$ Data input/output voltage	0	5.5	V
$T_A$ Operating free-air temperature	–40	85	°C

- NOTES: 6. All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.  
7. In applications with fast edge rates, multiple outputs switching, and operating at high frequencies, the output may have little or no level-shifting effect.



# SN74CBTD3384C

## 10-BIT FET BUS SWITCH WITH LEVEL SHIFTING

### 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V <sub>IK</sub>	Control inputs	V <sub>CC</sub> = 4.5 V,	I <sub>IN</sub> = -18 mA			-1.8	V
V <sub>IKU</sub>	Data inputs	V <sub>CC</sub> = 5 V,	0 mA > I <sub>I</sub> ≥ -50 mA, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch OFF			-2	V
V <sub>OH</sub>		See Figures 4 and 5					
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 5.5 V,	V <sub>IN</sub> = V <sub>CC</sub> or GND			±1	μA
I <sub>OZ</sub> ‡		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0 to 5.5 V, V <sub>I</sub> = 0, Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			±10	μA
I <sub>off</sub>		V <sub>CC</sub> = 0,	V <sub>O</sub> = 0 to 5.5 V, V <sub>I</sub> = 0			10	μA
I <sub>CC</sub>		V <sub>CC</sub> = 5.5 V,	I <sub>I/O</sub> = 0, V <sub>IN</sub> = V <sub>CC</sub> or GND, Switch ON or OFF			1.5	mA
ΔI <sub>CC</sub> §	Control inputs	V <sub>CC</sub> = 5.5 V,	One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND			2.5	mA
C <sub>in</sub>	Control inputs	V <sub>IN</sub> = 3 V or 0				3.5	pF
C <sub>io(OFF)</sub>		V <sub>I/O</sub> = 3 V or 0,	Switch OFF, V <sub>IN</sub> = V <sub>CC</sub> or GND			5	pF
C <sub>io(ON)</sub>		V <sub>I/O</sub> = 3 V or 0,	Switch ON, V <sub>IN</sub> = V <sub>CC</sub> or GND			12.5	pF
r <sub>on</sub> ¶		V <sub>CC</sub> = 4.5 V	V <sub>I</sub> = 0	I <sub>O</sub> = 64 mA	3	6	Ω
				I <sub>O</sub> = 30 mA	3	6	
			V <sub>I</sub> = 2.4 V,	I <sub>O</sub> = -15 mA	8	20	

V<sub>IN</sub> and I<sub>IN</sub> refer to control inputs. V<sub>I</sub>, V<sub>O</sub>, I<sub>I</sub>, and I<sub>O</sub> refer to data pins.

† All typical values are at V<sub>CC</sub> = 5 V (unless otherwise noted), T<sub>A</sub> = 25°C.

‡ For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

§ This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

¶ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	
t <sub>pd</sub> #	A or B	B or A	0.15		ns
t <sub>en</sub>	$\overline{OE}$	A or B	1.5	4.8	ns
t <sub>dis</sub>	$\overline{OE}$	A or B	1.5	4.8	ns

# The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



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undershoot characteristics (see Figures 1 and 2)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{OUTU}$	$V_{CC} = 5.5\text{ V}$ , Switch OFF, $V_{IN} = V_{CC}$ or GND	2	$V_{OH} - 0.3$		V

† All typical values are at  $V_{CC} = 5\text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

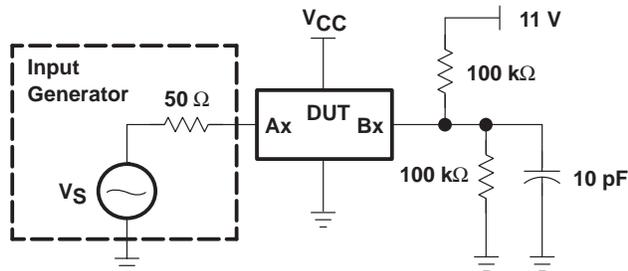


Figure 1. Device Test Setup

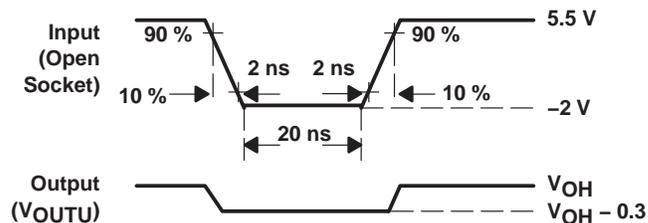
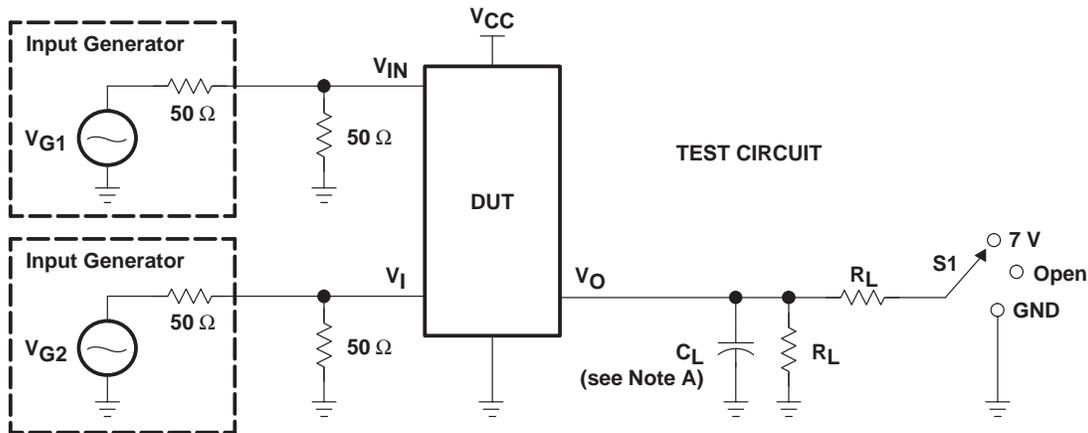


Figure 2. Transient Input Voltage ( $V_i$ ) and Output Voltage ( $V_{OUTU}$ ) Waveforms (Switch OFF)

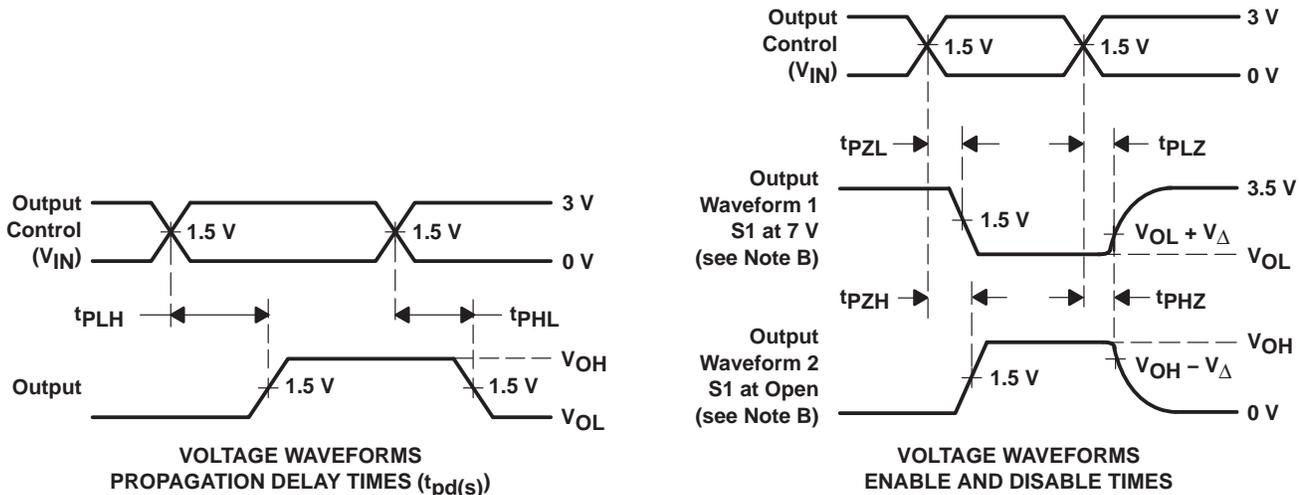
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**PARAMETER MEASUREMENT INFORMATION  
 FOR LEVEL SHIFTER**



TEST	VCC	S1	RL	VI	CL	VΔ
t <sub>pd</sub> (s)	5 V ± 0.5 V	Open	500 Ω	VCC or GND	50 pF	
t <sub>PLZ</sub> /t <sub>PZL</sub>	5 V ± 0.5 V	7 V	500 Ω	GND	50 pF	0.3 V
t <sub>PHZ</sub> /t <sub>PZH</sub>	5 V ± 0.5 V	Open	500 Ω	VCC	50 pF	0.3 V



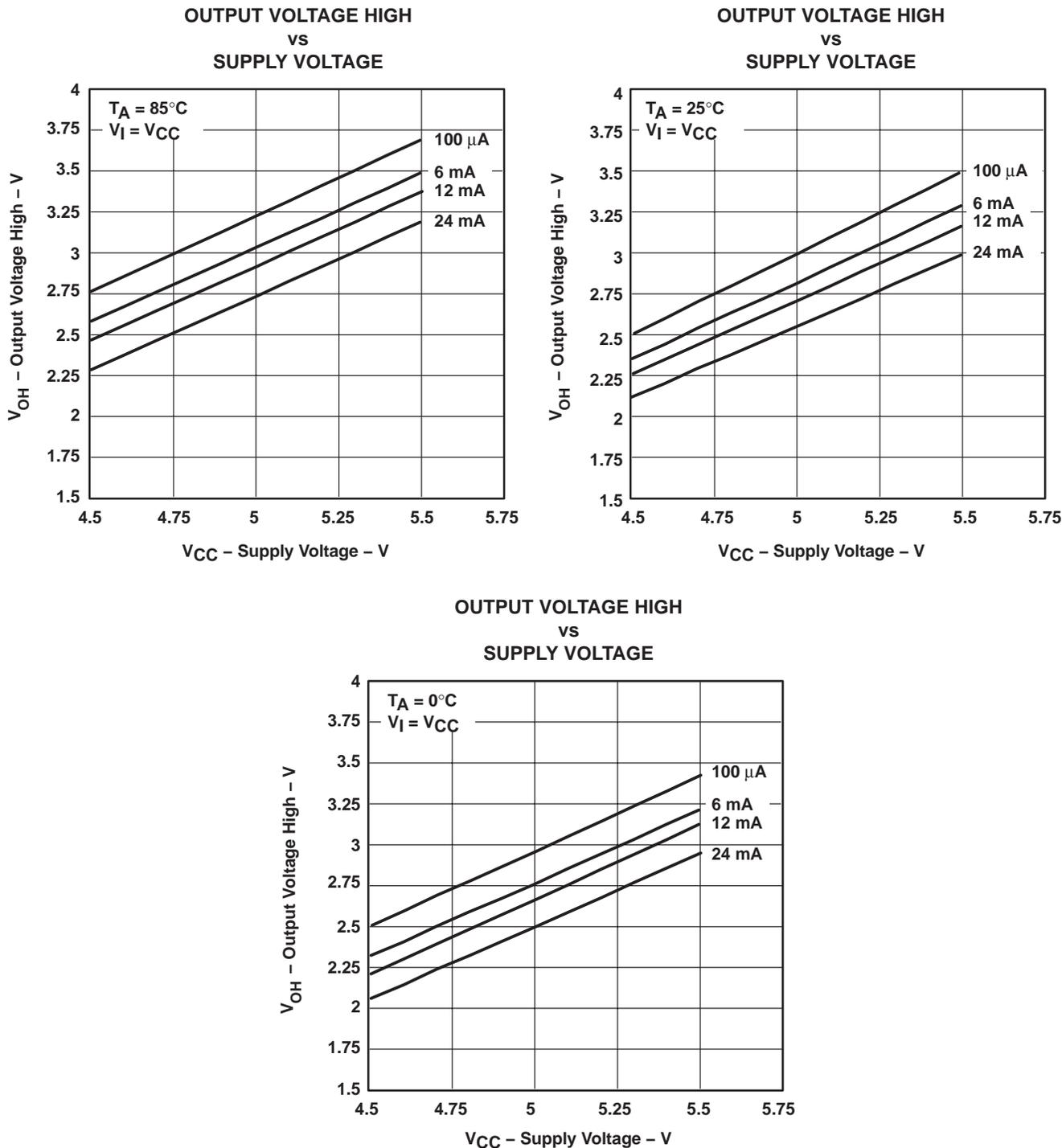
- NOTES:
- A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≤ 2.5 ns, t<sub>f</sub> ≤ 2.5 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>(s). The t<sub>pd</sub> propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
  - H. All parameters and waveforms are not applicable to all devices.

**Figure 3. Test Circuit and Voltage Waveforms**

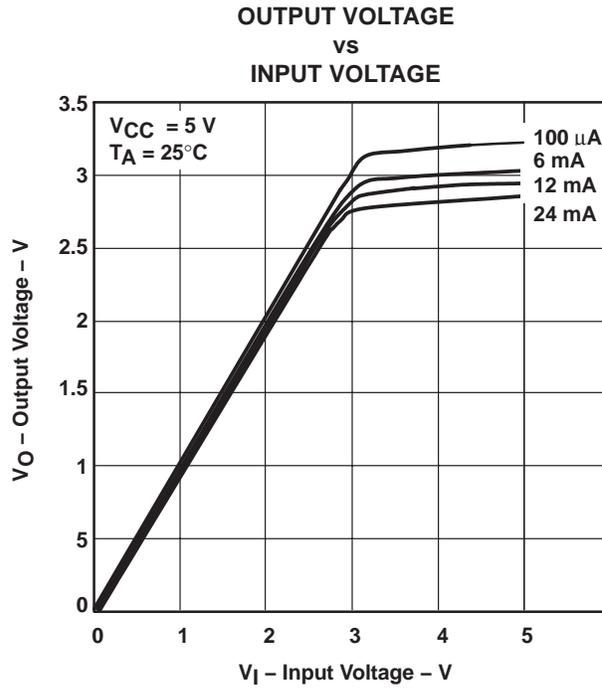
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**TYPICAL CHARACTERISTICS**



**TYPICAL CHARACTERISTICS (continued)**



**Figure 5. Data Output Voltage vs Data Input Voltage**

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
74CBTD3384CDGVRE4	ACTIVE	TVSOP	DGV	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>
74CBTD3384CDGVRG4	ACTIVE	TVSOP	DGV	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>
SN74CBTD3384CDBQR	ACTIVE	SSOP	DBQ	24	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CBTD3384C	<a href="#">Samples</a>
SN74CBTD3384CDBR	ACTIVE	SSOP	DB	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>
SN74CBTD3384CDGVR	ACTIVE	TVSOP	DGV	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>
SN74CBTD3384CDW	ACTIVE	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTD3384C	<a href="#">Samples</a>
SN74CBTD3384CDWR	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	CBTD3384C	<a href="#">Samples</a>
SN74CBTD3384CDWRE4	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTD3384C	<a href="#">Samples</a>
SN74CBTD3384CDWRG4	ACTIVE	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTD3384C	<a href="#">Samples</a>
SN74CBTD3384CPW	ACTIVE	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>
SN74CBTD3384CPWR	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>
SN74CBTD3384CPWRE4	ACTIVE	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CC384C	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

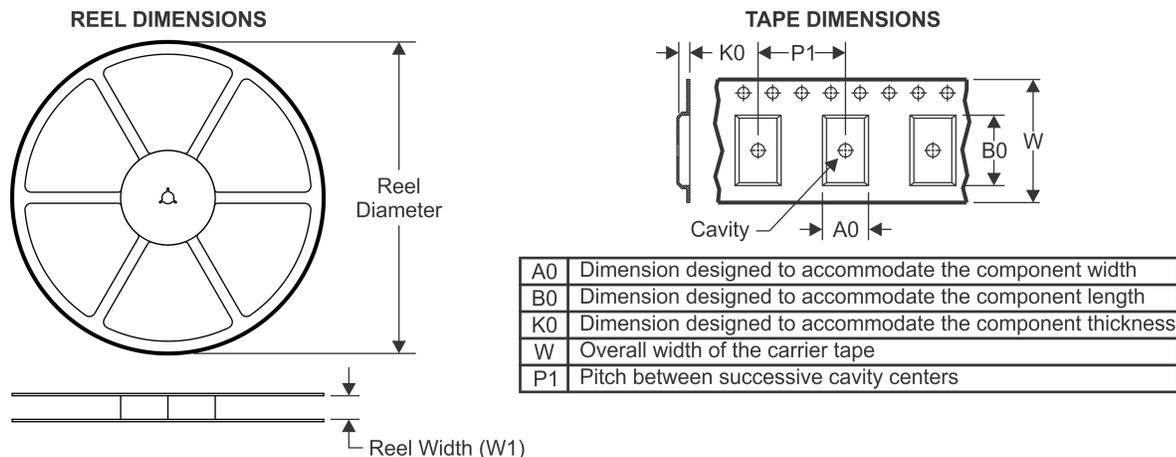
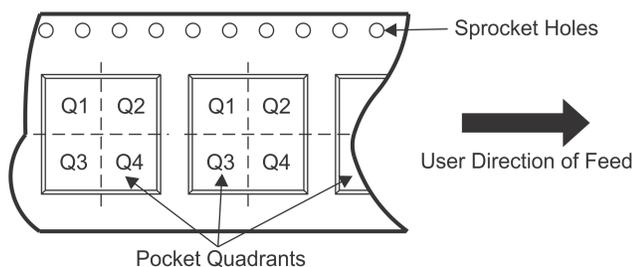
**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

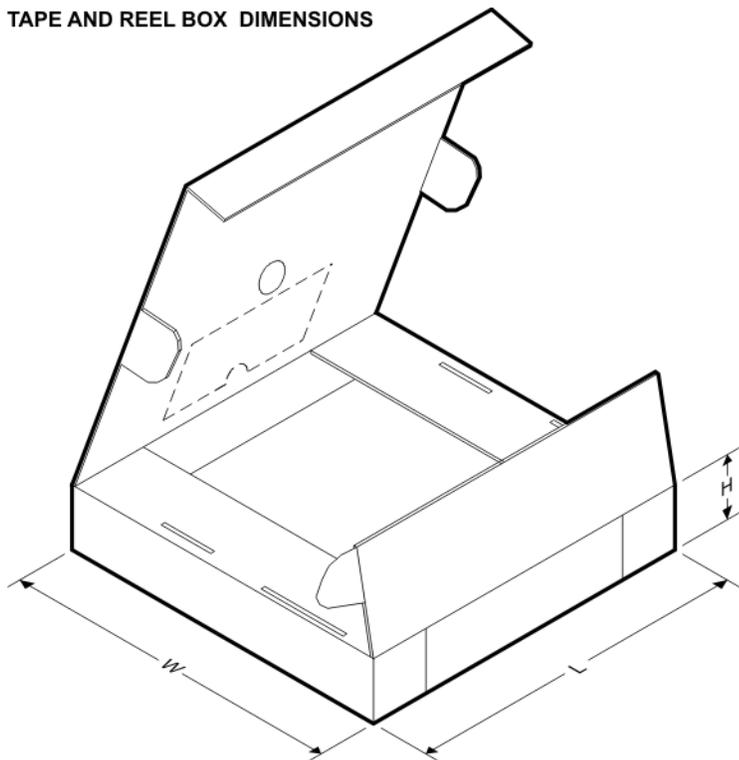
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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


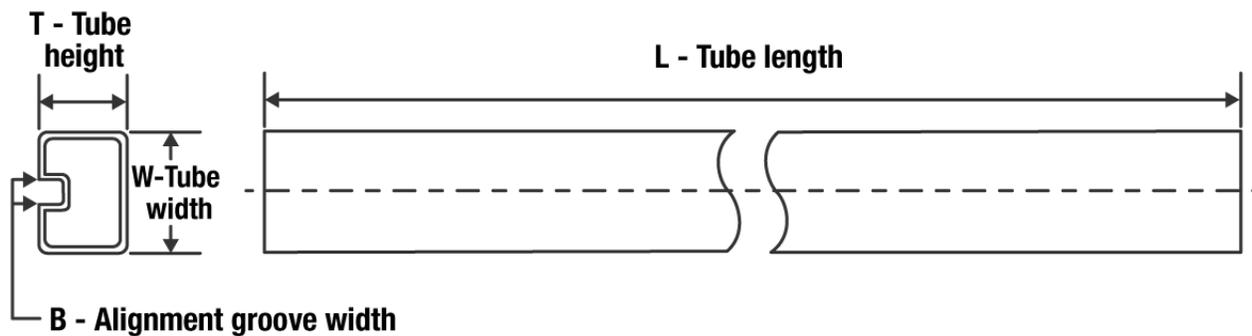
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBTD3384CDBQR	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CBTD3384CDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74CBTD3384CDGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CBTD3384CDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CBTD3384CDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CBTD3384CDWRG4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CBTD3384CPWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBTD3384CDBQR	SSOP	DBQ	24	2500	853.0	449.0	35.0
SN74CBTD3384CDBR	SSOP	DB	24	2000	853.0	449.0	35.0
SN74CBTD3384CDGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0
SN74CBTD3384CDWR	SOIC	DW	24	2000	364.0	361.0	36.0
SN74CBTD3384CDWR	SOIC	DW	24	2000	350.0	350.0	43.0
SN74CBTD3384CDWRG4	SOIC	DW	24	2000	350.0	350.0	43.0
SN74CBTD3384CPWR	TSSOP	PW	24	2000	853.0	449.0	35.0

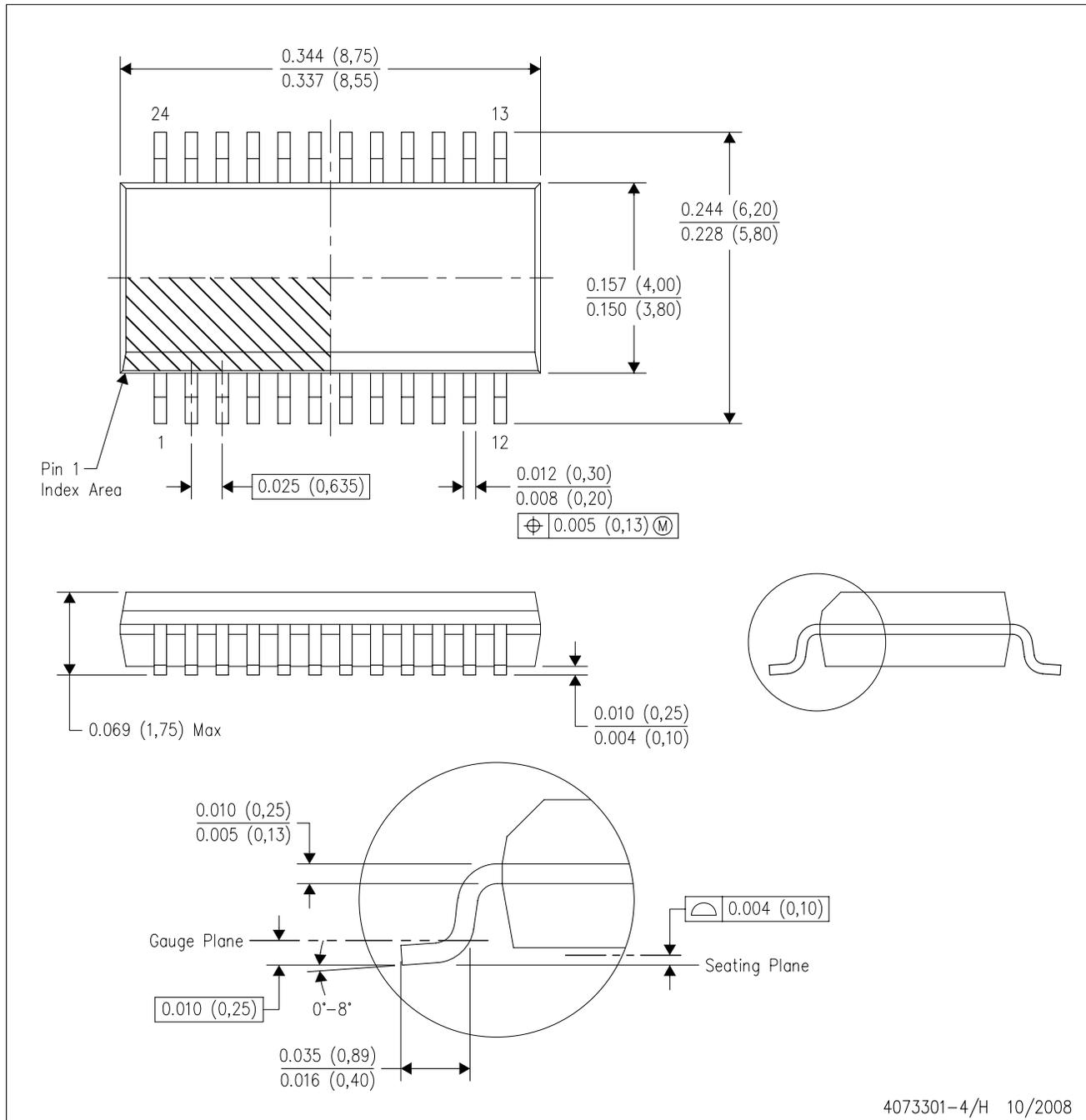
**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN74CBTD3384CDW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74CBTD3384CPW	PW	TSSOP	24	60	530	10.2	3600	3.5

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



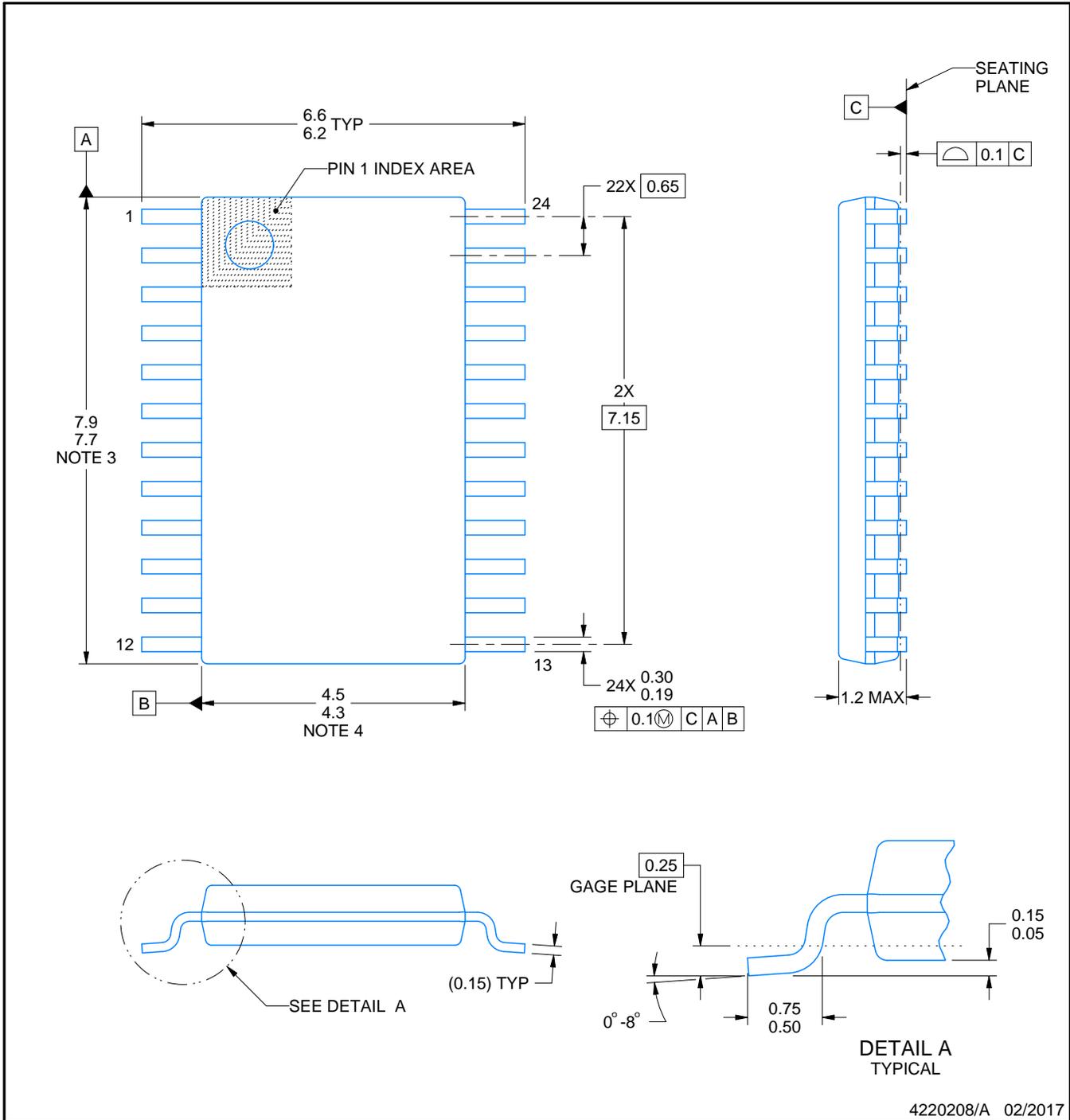
- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
  - D. Falls within JEDEC MO-137 variation AE.

PW0024A



**PACKAGE OUTLINE**  
**TSSOP - 1.2 mm max height**

SMALL OUTLINE PACKAGE



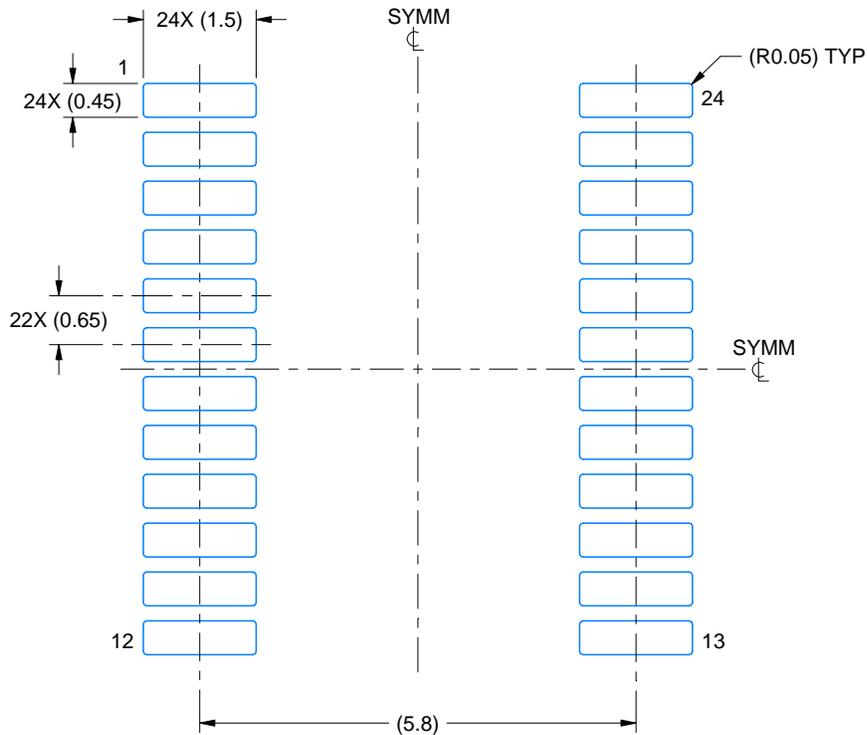
4220208/A 02/2017

# EXAMPLE BOARD LAYOUT

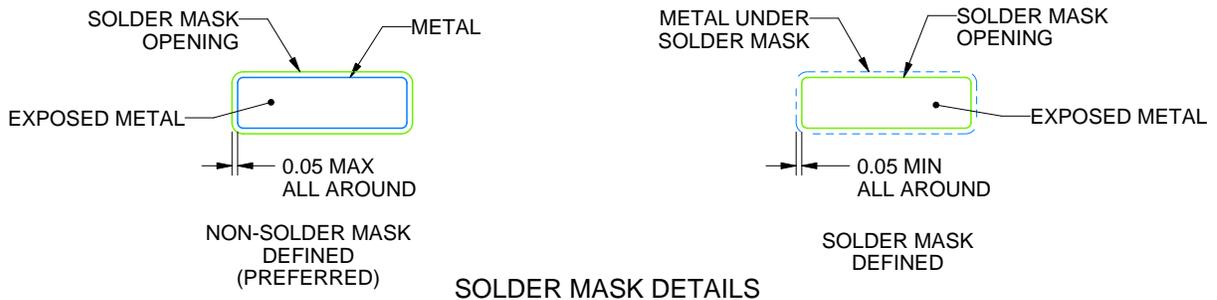
PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220208/A 02/2017

NOTES: (continued)

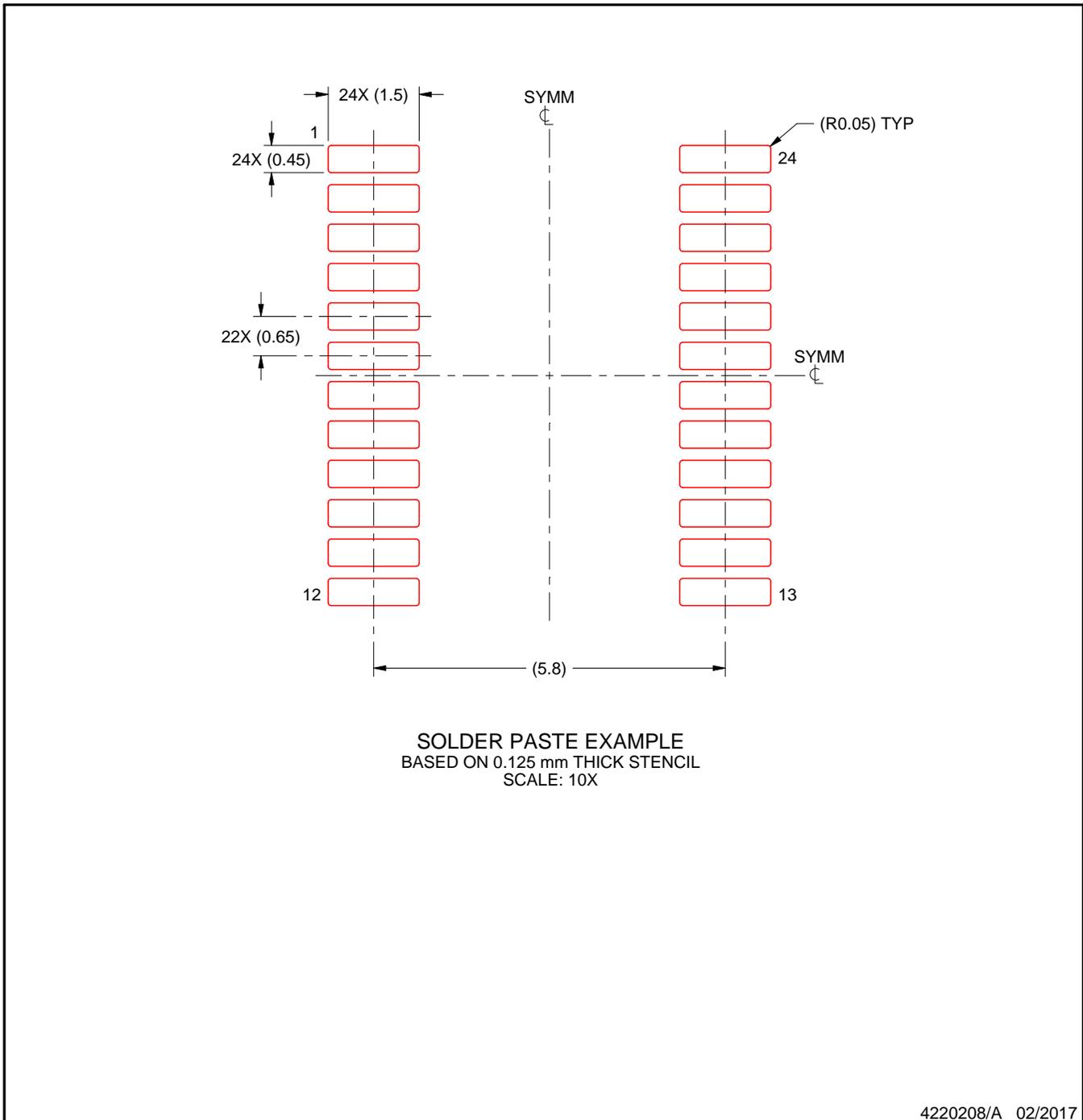
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220208/A 02/2017

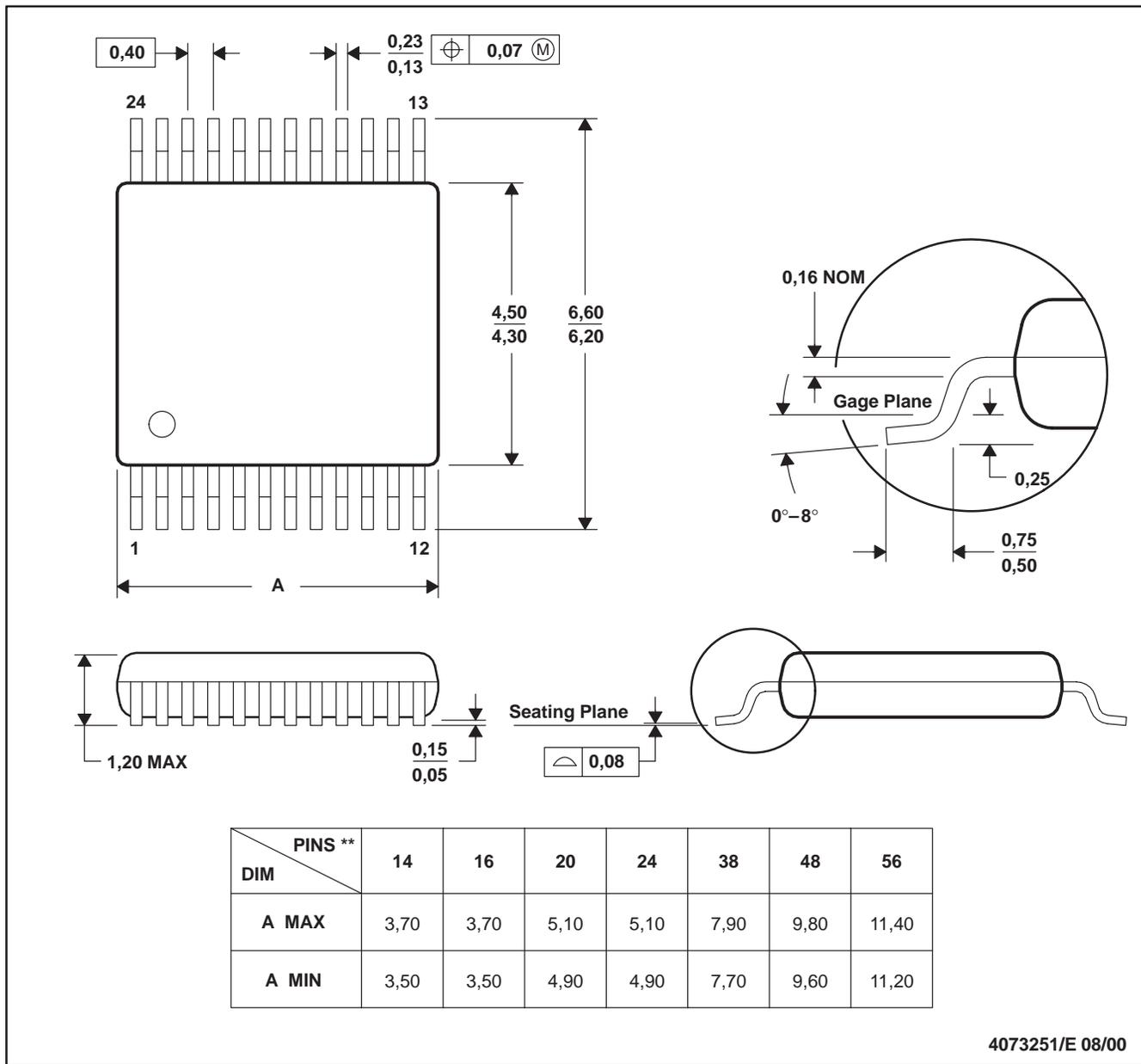
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGV (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

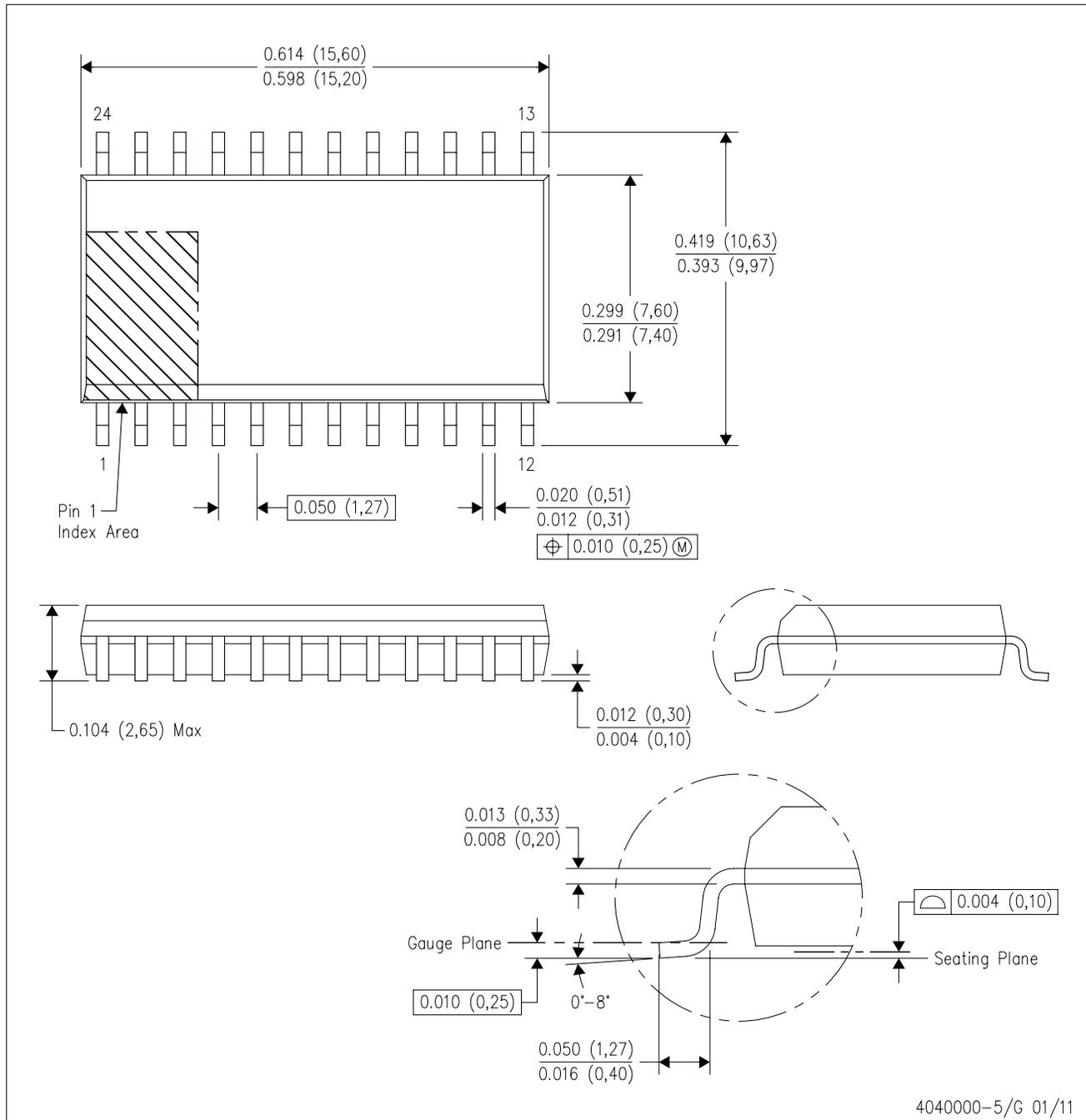
24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.  
 D. Falls within JEDEC: 24/48 Pins – MO-153  
 14/16/20/56 Pins – MO-194

DW (R-PDSO-G24)

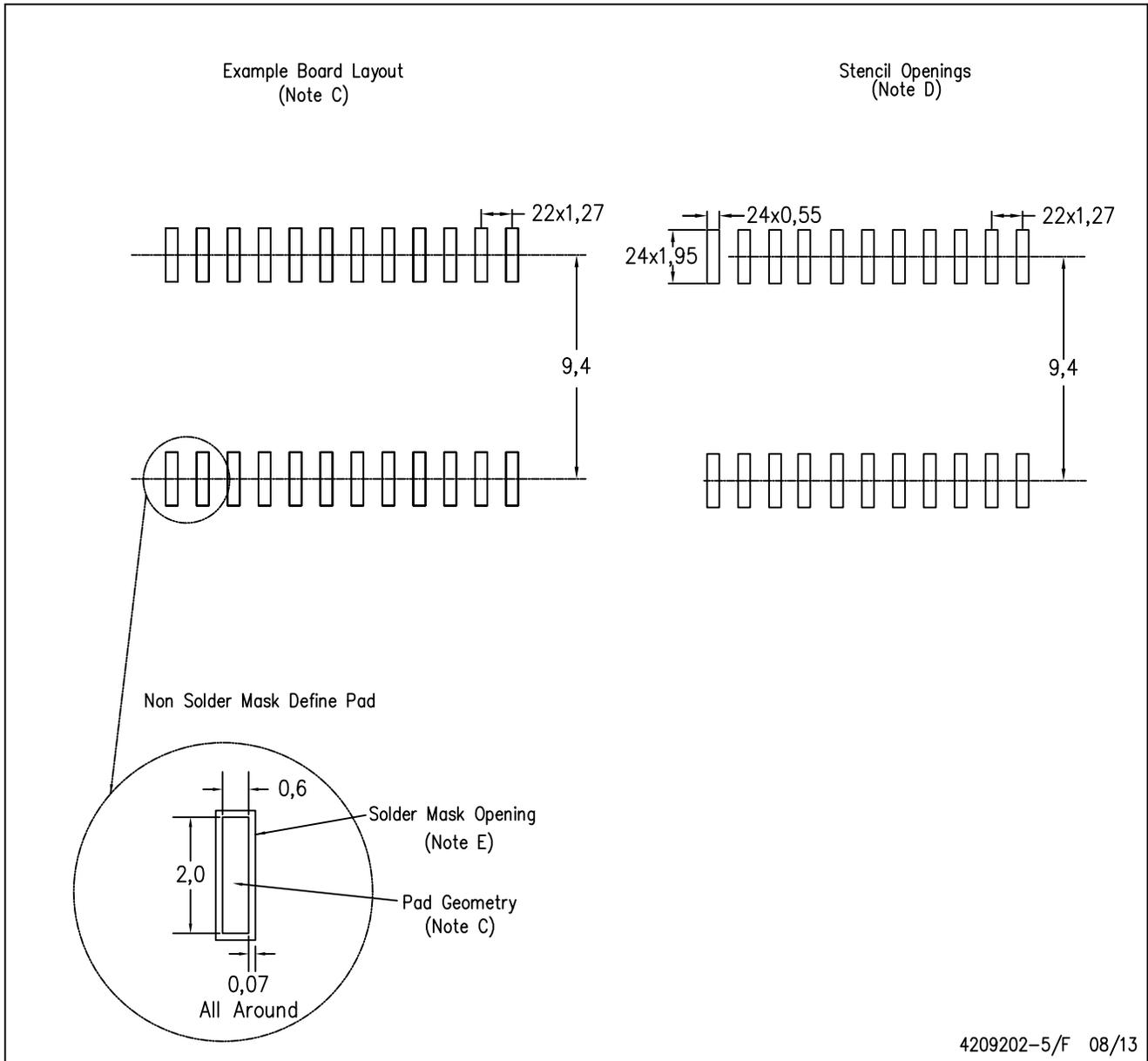
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AD.

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



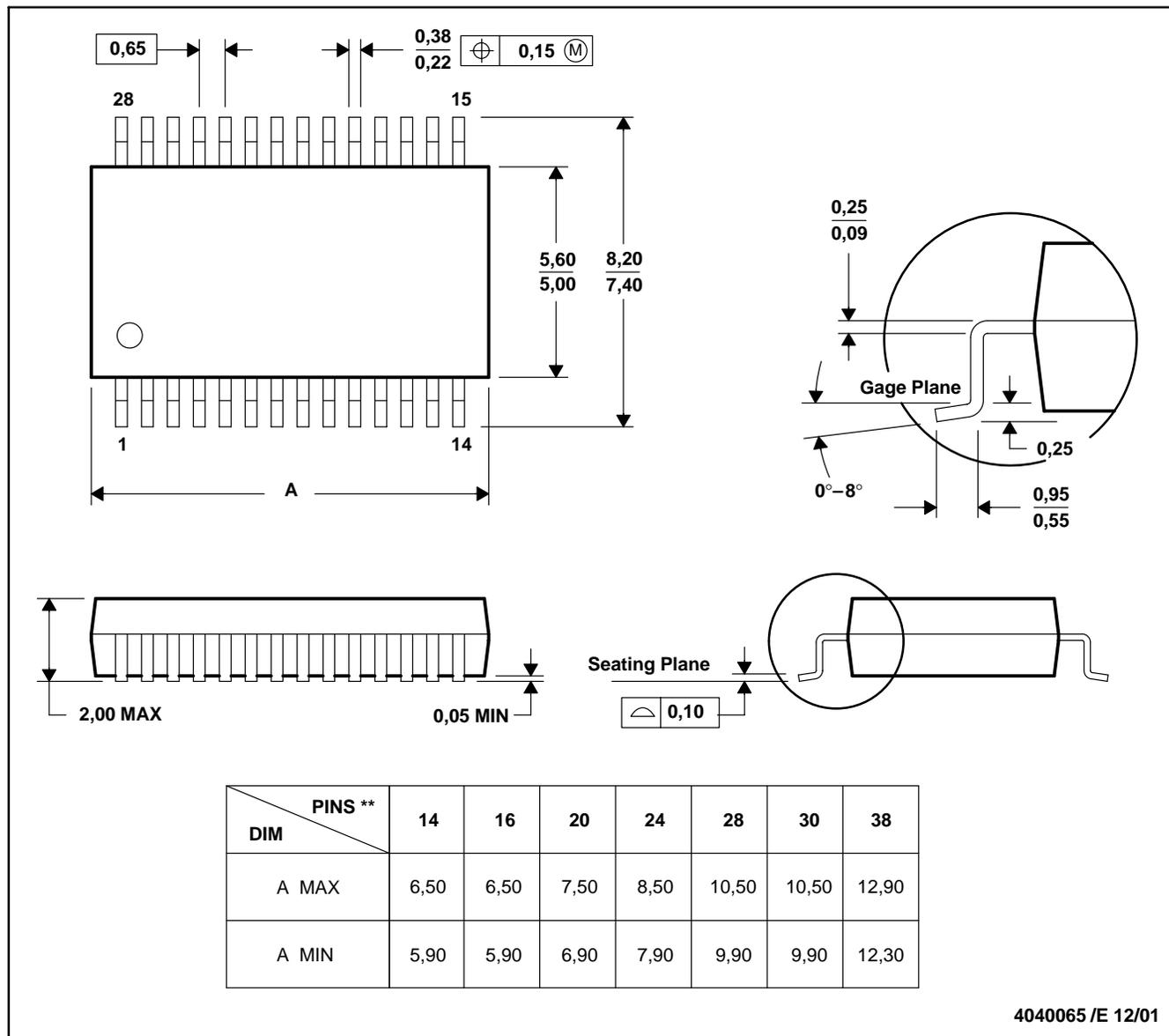
4209202-5/F 08/13

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Refer to IPC7351 for alternate board design.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-150

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